



Docket: 0756-958

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of )  
SHUNPEI YAMAZAKI et al. )  
Serial No. 08/183,800 ) Art Unit: 2811  
Filed: 01/21/94 ) Examiner: S. Crane  
For: SEMICONDUCTOR MATERIAL AND )  
METHOD FOR FORMING THE SAME AND )  
THIN FILM TRANSISTOR )

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Assistant Commissioner For Patents Washington, D.C. 20231, on

12-29-98

*George S. Lofstrom*

*#41*  
*Franklin*  
*E. McMillan*  
*12/29/98*

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JAN 12 1999

GROUP 2100

AMENDMENT

Honorable Assistant Commissioner for Patents  
Washington, D.C. 20231

Sir:

In response to the *Office Action* mailed on September 29, 1998, please amend the above-identified application as follows:

01/11/1999 ZABDALLA 00000035 08183800

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*FEB 24 1999*

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